

16 A Three-quadrant triacs high commutation Rev. 01 — 11 April 2007

Product data sheet

1. **Product profile**

1.1 General description

Passivated, new generation, high commutation triacs in a SOT186A isolated full pack plastic package

1.2 Features

- Very high commutation performance maximized at each gate sensitivity
- High isolation voltage

1.3 Applications

- High power motor control e.g. washing Refrigeration and air conditioning machines and vacuum cleaners
- Non-linear rectifier-fed motor loads.

1.4 Quick reference data

- V_{DRM} \leq 600 V (BTA316X-600B/C/E)
- V_{DRM} ≤ 800 V (BTA316X-800B/C/E)
- I_{TSM} \leq 140 A (t = 20 ms)
- I_{T(RMS)} \leq 16 A

- High immunity to dV/dt
- Wide range of gate sensitivities
- compressors
- Electronic thermostats

2 SOT186A (TO-220F)

- I_{GT} \leq 50 mA (BTA316X series B)
- I_{GT} ≤ 35 mA (BTA316X series C)
- I_{GT} \leq 10 mA (BTA316X series E)

Pinning information 2.

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		
2	main terminal 2 (T2)	mb	T2-T1
3	gate (G)		Sym051
mb	mounting base; isolated		
		ĨĨ	



16 A Three-quadrant triacs high commutation

3. Ordering information

Type number	Package								
	Name	Description	Version						
BTA316X-600B	TO-220F	20F plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'							
BTA316X-600C									
BTA316X-600E									
BTA316X-800B									
BTA316X-800C									
BTA316X-800E									

4. Limiting values

Table 3. Limiting values

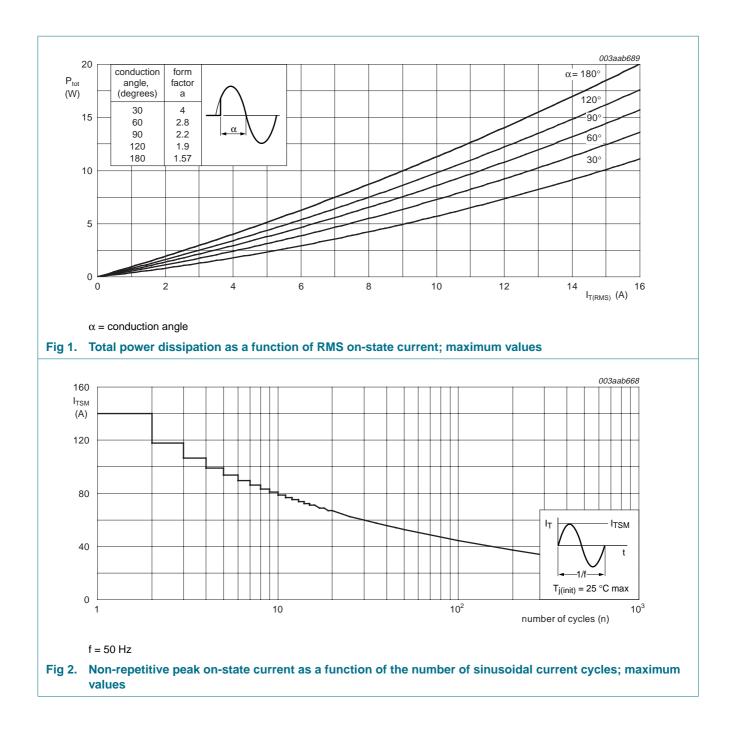
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage	BTA316X-600B; BTA316X-600C; BTA316X-600E	<u>[1]</u> _	600	V
	BTA316X-800B; BTA316X-800C; BTA316X-800E	-	800	V	
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 45 °C; see <u>Figure 4</u> and <u>5</u>	-	16	A
I _{TSM} non-repetitive peak on-state current		full sine wave; $T_j = 25 \text{ °C prior to}$ surge; see Figure 2 and 3			
		t = 20 ms	-	140	А
		t = 16.7 ms	-	150	А
l ² t	l ² t for fusing	t = 10 ms	-	98	A ² s
dl _T /dt	rate of rise of on-state current	$\begin{split} I_{TM} &= 20 \text{ A}; \text{ I}_{G} = 0.2 \text{ A}; \\ dI_{G}/dt &= 0.2 \text{ A}/\mu \text{s} \end{split}$	-	100	A/μs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/μs.

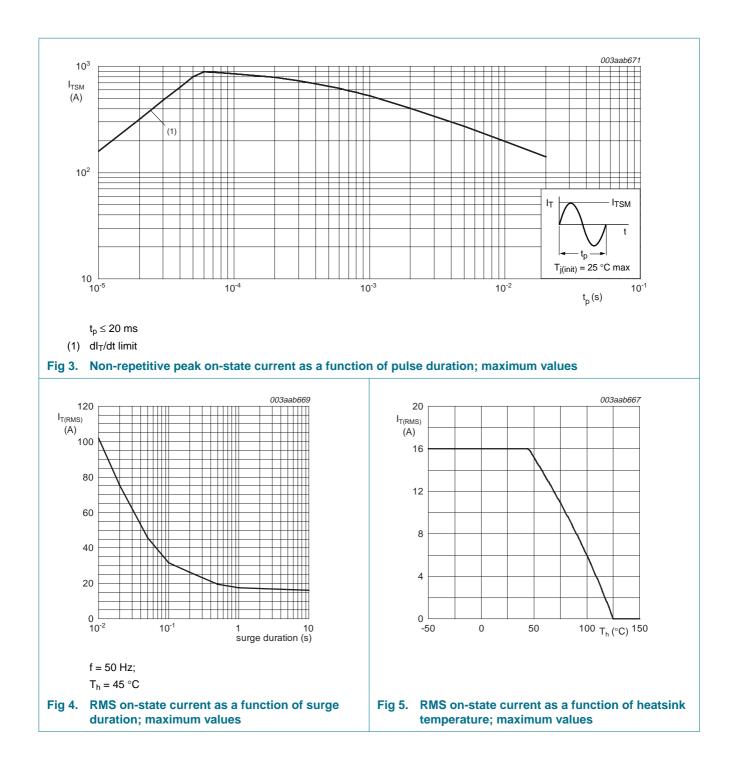
BTA316X series B, C and E

16 A Three-quadrant triacs high commutation



BTA316X series B, C and E

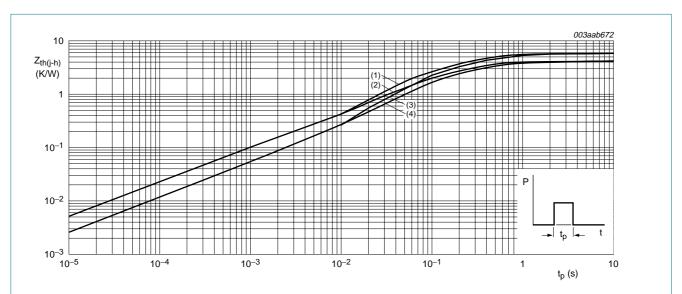
16 A Three-quadrant triacs high commutation



16 A Three-quadrant triacs high commutation

5. Thermal characteristics

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	full or half cycle without heatsink compound; see <u>Figure 6</u>	-	-	5.5	K/W
		full or half cycle with heatsink compound; see Figure 6	-	-	4.0	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W



- (1) Unidirectional (half cycle) without heatsink compound
- (2) Unidirectional (half cycle) with heatsink compound
- (3) Bidirectional (full cycle) without heatsink compound
- (4) Bidirectional (full cycle) with heatsink compound
- Fig 6. Transient thermal impedance from junction to heatsink as a function of pulse duration

6. Isolation characteristics

Table 5. Isolation limiting values and characteristics $T = 25 \degree$ C unloss otherwise specified

$T_h = 25 ^{\circ}C unless$	s otherwise sp	ecified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol} (RMS)	RMS isolation voltage	from all three terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; RH \leq 65 %; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from pin 2 to external heatsink; f = 1 MHz	-	10	-	pF

16 A Three-quadrant triacs high commutation

7. Static characteristics

Table 6.Static characteristics

 $T_i = 25 \circ C$ unless otherwise specified.

Symbol	Parameter	Conditions		A316X- A316X-		BTA316X-600C BTA316X-800C				BTA316X-600E BTA316X-800E		
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	_
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; see <u>Figure 8</u>										
		T2+ G+	2	-	50	2	-	35	-	-	10	mA
		T2+ G–	2	-	50	2	-	35	-	-	10	mA
		T2– G–	2	-	50	2	-	35	-	-	10	mA
IL latching current	latching current	$V_D = 12 V;$ I _{GT} = 0.1 A; see <u>Figure 10</u>										
		T2+ G+	-	-	60	-	-	50	-	-	25	mA
		T2+ G–	-	-	90	-	-	60	-	-	30	mA
		T2– G–	-	-	60	-	-	50	-	-	30	mA
I _H	holding current	$V_D = 12 V;$ I _{GT} = 0.1 A; see <u>Figure 11</u>	-	-	60	-	-	35	-	-	15	mA
V _T	on-state voltage	I _T = 18 A; see <u>Figure 9</u>	-	1.3	1.5	-	1.3	1.5	-	1.3	1.5	V
	gate trigger voltage	$V_D = 12 V;$ $I_T = 0.1 A;$ see <u>Figure 7</u>	-	0.8	1.5	-	0.8	1.5	-	0.8	1.5	V
		$V_D = 400 V;$ $I_T = 0.1 A;$ $T_j = 125 \ ^{\circ}C$	0.25	0.4	-	0.25	0.4	-	0.25	0.4	-	V
I _D	off-state current	$V_D = V_{DRM(max)};$ $T_j = 125 \ ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	-	0.1	0.5	mA

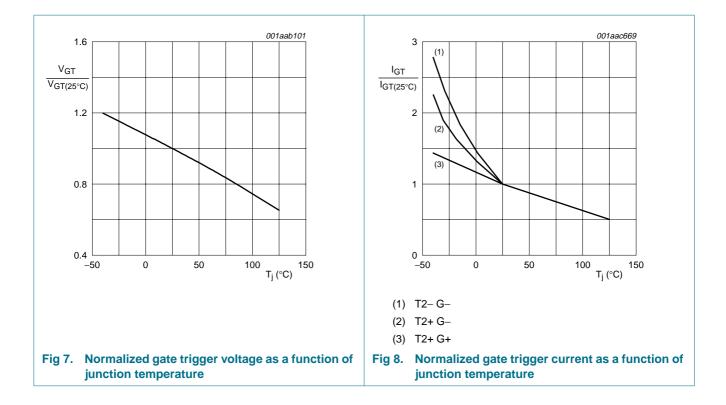
16 A Three-quadrant triacs high commutation

8. Dynamic characteristics

Symbol	Parameter	Conditions		BTA316X-600B BTA316X-800B		BTA316X-600C BTA316X-800C		BTA316X-600E BTA316X-800E			Unit	
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
dV _D /dt	rate of rise of off-state voltage	$\begin{split} V_{DM} &= 0.67 \times \\ V_{DRM(max)}; \\ T_j &= 125 \ ^\circ\text{C}; \\ exponential \\ waveform; gate open \\ circuit \end{split}$	1000	-	-	500	-	-	60	-	-	V/µs
of	commutating	$\label{eq:VDM} \begin{split} V_{DM} &= 400 \text{ V};\\ T_j &= 125 \ ^\circ\text{C};\\ I_{T(RMS)} &= 16 \text{ A};\\ \text{without snubber};\\ \text{gate open circuit} \end{split}$	20	-	-	15	-	-	5	-	-	A/ms
		$V_{DM} = 400 \text{ V};$ $T_j = 125 \text{ °C};$ $I_{T(RMS)} = 16 \text{ A};$ $dV/dt = 10 \text{ V}/\mu \text{s};$ gate open circuit	-	-	-	-	-	-	8	-	-	A/ms
		$\begin{split} V_{DM} &= 400 \text{ V}; \\ T_{j} &= 125 \text{ °C}; \\ I_{T(RMS)} &= 16 \text{ A}; \\ dV/dt &= 1 \text{ V}/\mu \text{s}; \text{ gate} \\ \text{open circuit} \end{split}$	-	-	-	-	-	-	12	-	-	A/ms
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 20 \text{ A};\\ V_D &= V_{DRM(max)};\\ I_G &= 0.1 \text{ A};\\ dI_G/dt &= 5 \text{ A}/\mu\text{s} \end{split}$	-	2	-	-	2	-	-	2	-	μs

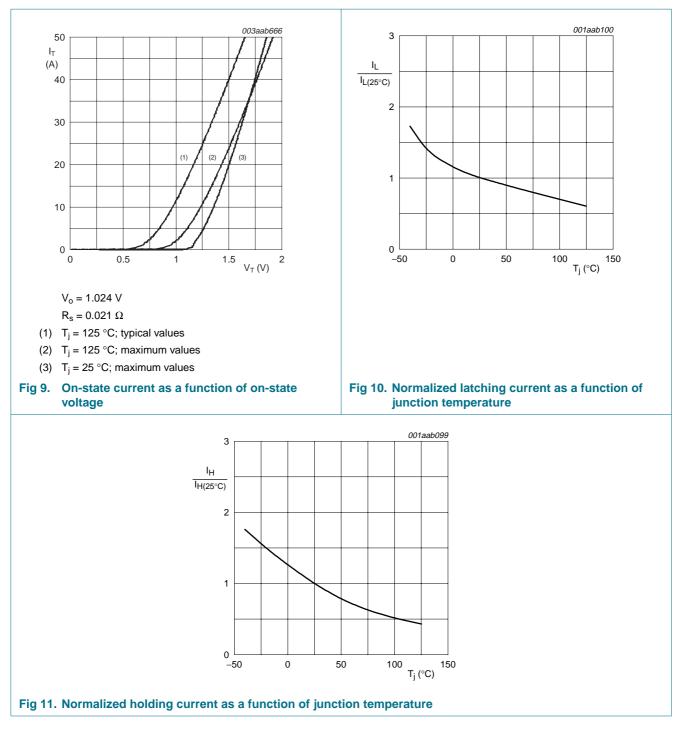
BTA316X series B, C and E

16 A Three-quadrant triacs high commutation



BTA316X series B, C and E

16 A Three-quadrant triacs high commutation



9. Package information

Epoxy meets UL94 V-0 at 3.175 mm

BTA316X_SER_B_C_E_1

BTA316X series B, C and E

16 A Three-quadrant triacs high commutation

10. Package outline

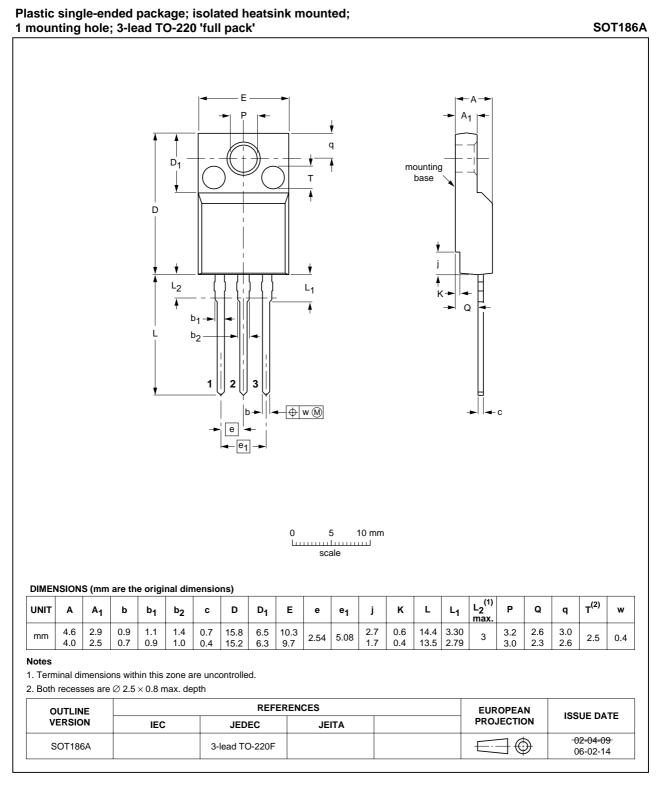


Fig 12. Package outline SOT186A (TO-220F)

16 A Three-quadrant triacs high commutation

11. Revision history

Table 8. Revision histor	у			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA316X_SER_B_C_E_1	20070411	Product data sheet	-	-

16 A Three-quadrant triacs high commutation

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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16 A Three-quadrant triacs high commutation

14. Contents

1	Product profile 1
1.1	General description
1.2	Features 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 1
3	Ordering information 2
4	Limiting values 2
5	Thermal characteristics 5
6	Isolation characteristics 5
7	Static characteristics 6
8	Dynamic characteristics 7
9	Package information 9
10	Package outline 10
11	Revision history 11
12	Legal information 12
12.1	Data sheet status 12
12.2	Definitions 12
12.3	Disclaimers
12.4	Trademarks 12
13	Contact information 12
14	Contents 13

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